

REMARKS

In response to the election requirement in the Office Action of July 23, 2003, Applicant hereby elects without traverse the Species I, directed to a method for manufacturing a semiconductor device having the step of forming the barrier layer and the third semiconductor film utilize the third semiconductor film as a gettering site to reduce the metal element/crystallization promote material from the first semiconductor film. Claims 107-179 read on the elected species.

Claims 212-262 are canceled.

Examination on the merits is requested.

Respectfully submitted,



Eric J. Robinson
Reg. No. 38,285

Robinson Intellectual Property Law Office, P.C.
PMB 955
21010 Southbank Street
Potomac Falls, Virginia 20165
(571) 434-6789